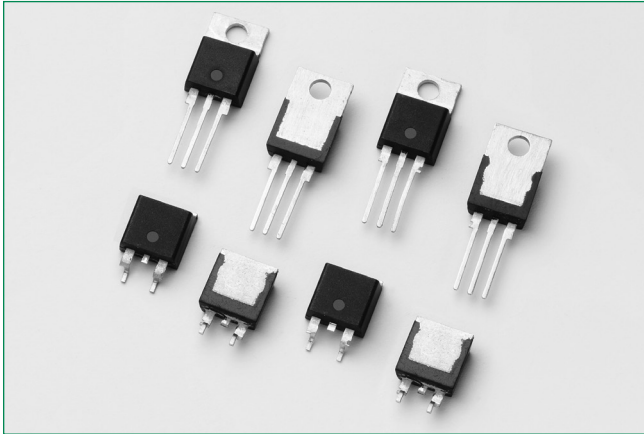


# SVxx16xx series

## 16 Amp High Junction Temperature SCRs



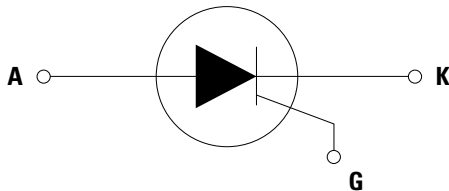
### Agency Approval

| Agency | Agency File Number |
|--------|--------------------|
|        | L Packages: E71639 |

### Main Features

| Symbol            | Value   | Unit |
|-------------------|---------|------|
| $I_{T(RMS)}$      | 16      | A    |
| $V_{DRM}/V_{RRM}$ | 600     | V    |
| $I_{GT}$          | 6 to 10 | mA   |

### Schematic Symbol



### Description

The SVxx16xx high junction temperature SCR series is ideal for uni-directional switch applications such as phase control in heating, motor speed controls, converters/rectifiers and inrush current controllers.

These SCRs have a low gate current, ( $I_{GT}$ ) trigger level of 6mA and 10mA maximum at approximately 1.5V for SVxx16x1 and SVxx16x2, respectively.

### Features & Benefits

- Halogen free and RoHS compliant
- 150°C maximum junction temperature
- Surge capability up to 225A at 60 Hz half cycle
- High dv/dt performance
- UL Recognized to UL 1557 as an Electrically Isolated Semiconductor Device

### Applications

Typical applications include AC Generator (ACG) rectifiers, battery voltage regulators, generic converters and inrush current controller in various AC and DC applications. Additional applications include controls for power tools, home/brown good and white goods appliances.

Internally constructed isolated packages are offered for ease of heat sinking with high isolation voltage.

# SVxx16xx series

## 16 Amp High Junction Temperature SCRs

### Absolute Maximum Ratings — Standard SCRs

| Symbol            | Parameter                                 | Test Conditions                                                                                                                                                          | Value        | Unit                   |
|-------------------|-------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------|------------------------|
| $V_{DSM}/V_{RSM}$ | Peak non-repetitive blocking voltage      | PW=100 $\mu$ s                                                                                                                                                           | 800          | V                      |
| $I_{T(RMS)}$      | RMS on-state current                      | SVxx16Lx $T_C = 110^\circ\text{C}$<br>SVxx16Rx $T_C = 135^\circ\text{C}$<br>SVxx16Nx                                                                                     | 16<br>16     | A                      |
| $I_{T(AV)}$       | Average on-state current                  | SVxx16Lx $T_C = 110^\circ\text{C}$<br>SVxx16Rx $T_C = 135^\circ\text{C}$<br>SVxx16Nx                                                                                     | 10.2<br>10.2 | A                      |
| $I_{TSM}$         | Peak non-repetitive surge current         | single half cycle; $f = 50\text{Hz}$ ;<br>$T_J(\text{initial}) = 25^\circ\text{C}$<br>single half cycle; $f = 60\text{Hz}$ ;<br>$T_J(\text{initial}) = 25^\circ\text{C}$ | 188<br>225   | A                      |
| $I^2t$            | $I^2t$ Value for fusing                   | $t_p = 8.3\text{ ms}$                                                                                                                                                    | 210          | $\text{A}^2\text{s}$   |
| $di/dt$           | Critical rate of rise of on-state current | $f = 60\text{ Hz}$ ; $T_J = 150^\circ\text{C}$                                                                                                                           | 100          | $\text{A}/\mu\text{s}$ |
| $I_{GM}$          | Peak gate current                         | $T_J = 150^\circ\text{C}$                                                                                                                                                | 4            | A                      |
| $P_{G(AV)}$       | Average gate power dissipation            | $T_J = 150^\circ\text{C}$                                                                                                                                                | 0.8          | W                      |
| $T_{stg}$         | Storage temperature range                 |                                                                                                                                                                          | -40 to 150   | $^\circ\text{C}$       |
| $T_J$             | Operating junction temperature range      |                                                                                                                                                                          | -40 to 150   | $^\circ\text{C}$       |

Note: xx=voltage/10, x=sensitivity

### Electrical Characteristics ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)

| Symbol   | Test Conditions                                                                                                 |      | SVxx16x1 | SVxx16x2 | Unit                   |
|----------|-----------------------------------------------------------------------------------------------------------------|------|----------|----------|------------------------|
| $I_{GT}$ | $V_D = 12\text{V}$ ; $R_L = 60\ \Omega$                                                                         | MIN. | 2        | 5        | mA                     |
|          |                                                                                                                 | MAX. | 6        | 10       |                        |
| $V_{GT}$ |                                                                                                                 | MAX. | 1.5      | 1.5      | V                      |
| $dv/dt$  | $V_D = 67\%V_{DRM}$ ; gate open; $T_J = 125^\circ\text{C}$                                                      | MIN. | 400      | 800      | $\text{V}/\mu\text{s}$ |
|          | $V_D = 67\%V_{DRM}$ ; gate open; $T_J = 150^\circ\text{C}$                                                      |      | 200      | 400      |                        |
| $V_{GD}$ | $V_D = V_{DRM}$ ; $R_L = 3.3\text{ k}\Omega$ ; $T_J = 150^\circ\text{C}$                                        | MIN. | 0.2      | 0.2      | V                      |
| $I_H$    | $I_T = 200\text{mA}$ (initial)                                                                                  | MAX. | 22       | 35       | mA                     |
| $t_q$    | $I_T = 2\text{A}$ ; $t_p = 50\mu\text{s}$ ; $dv/dt = 5\text{V}/\mu\text{s}$ ; $di/dt = -30\text{A}/\mu\text{s}$ | MAX. | 25       | 25       | $\mu\text{s}$          |
| $t_{gt}$ | $I_G = 2 \times I_{GT}$ ; $P_W = 15\mu\text{s}$ ; $I_T = 32\text{A}$                                            | TYP. | 2.6      | 2.6      | $\mu\text{s}$          |

Note: xx=voltage/10, x=package

### Static Characteristics

| Symbol              | Test Conditions                               | Value                     | Unit  |
|---------------------|-----------------------------------------------|---------------------------|-------|
| $V_{TM}$            | $I_T = 32\text{A}$ ; $t_p = 380\ \mu\text{s}$ | MAX.                      | 1.6 V |
| $I_{DRM} / I_{RRM}$ | $V_{DRM} = V_{RRM}$                           | $T_J = 25^\circ\text{C}$  | 10    |
|                     |                                               | $T_J = 125^\circ\text{C}$ | 1000  |
|                     |                                               | $T_J = 150^\circ\text{C}$ | 3000  |

### Thermal Resistances

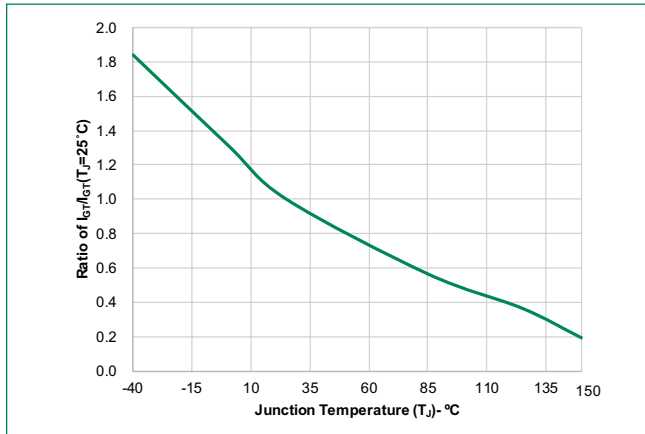
| Symbol           | Parameter             | Value                | Unit                      |
|------------------|-----------------------|----------------------|---------------------------|
| $R_{\theta(JC)}$ | Junction to case (AC) | SVxx16Rx<br>SVxx16Nx | 1.0                       |
|                  |                       | SVxx16Lx             | 2.5                       |
|                  |                       |                      | $^\circ\text{C}/\text{W}$ |

Note: xx=voltage/10, x=sensitivity

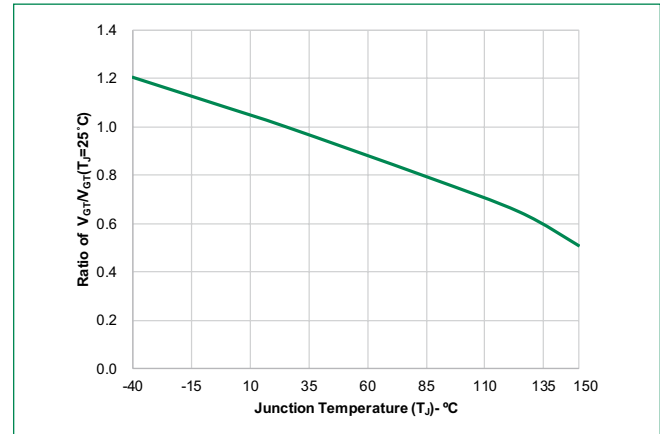
# SVxx16xx series

## 16 Amp High Junction Temperature SCRs

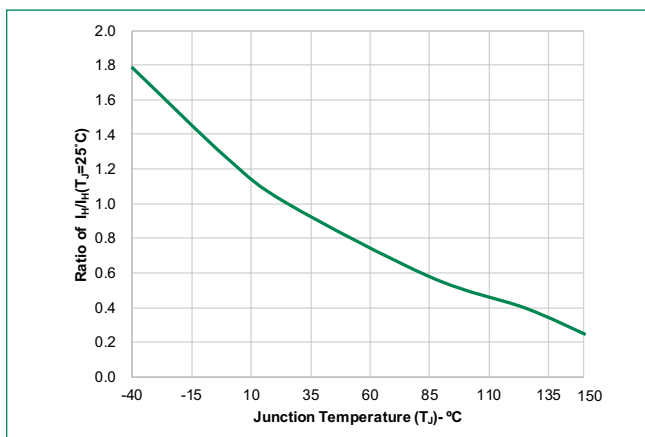
**Figure 1:**  
Normalized DC Gate Trigger Current  
vs. Junction Temperature



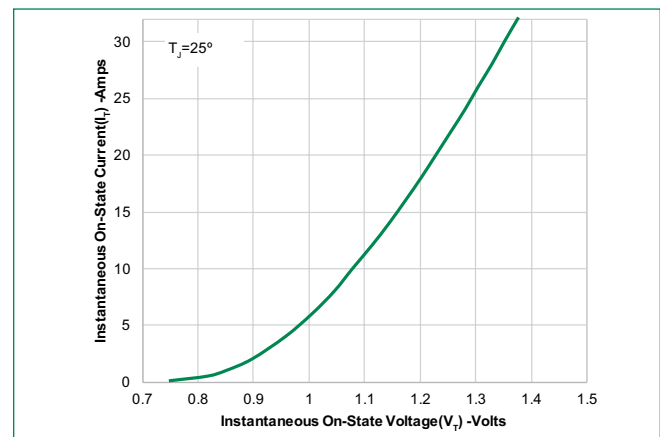
**Figure 2:**  
Normalized DC Gate Trigger Voltage  
vs. Junction Temperature



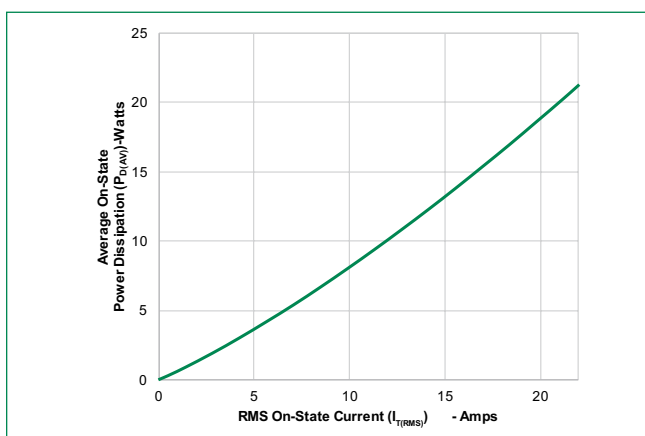
**Figure 3:**  
Normalized DC Holding Current vs. Junction Temperature



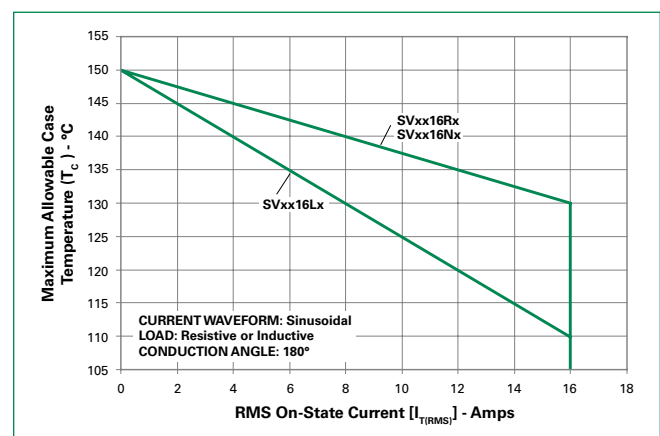
**Figure 4:**  
On-State Current vs. On-State Voltage (Typical)



**Figure 5:**  
Power Dissipation (Typical) vs. RMS On-State Current



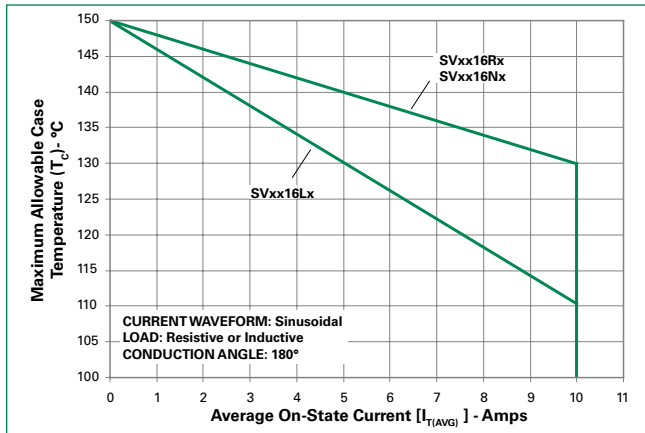
**Figure 6:**  
Maximum Allowable Case Temperature  
vs. RMS On-State Current



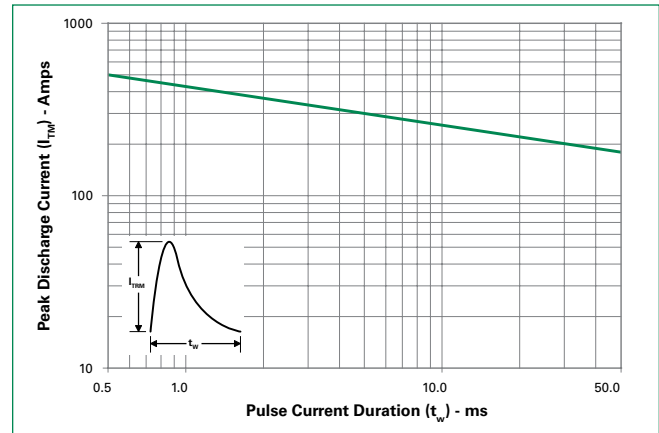
# SVxx16xx series

## 16 Amp High Junction Temperature SCRs

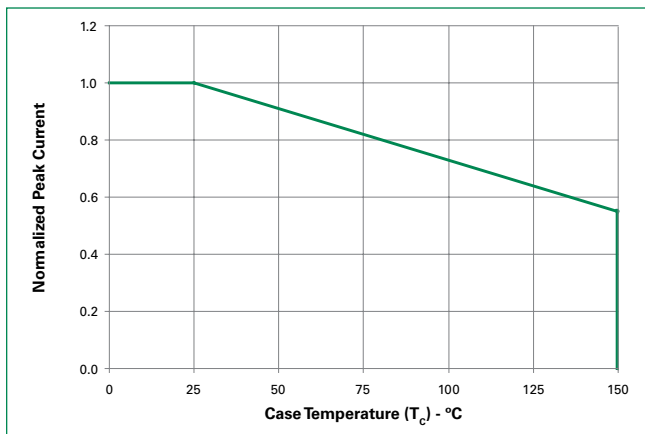
**Figure 7:**  
Maximum Allowable Case Temperature  
vs. Average On-State Current



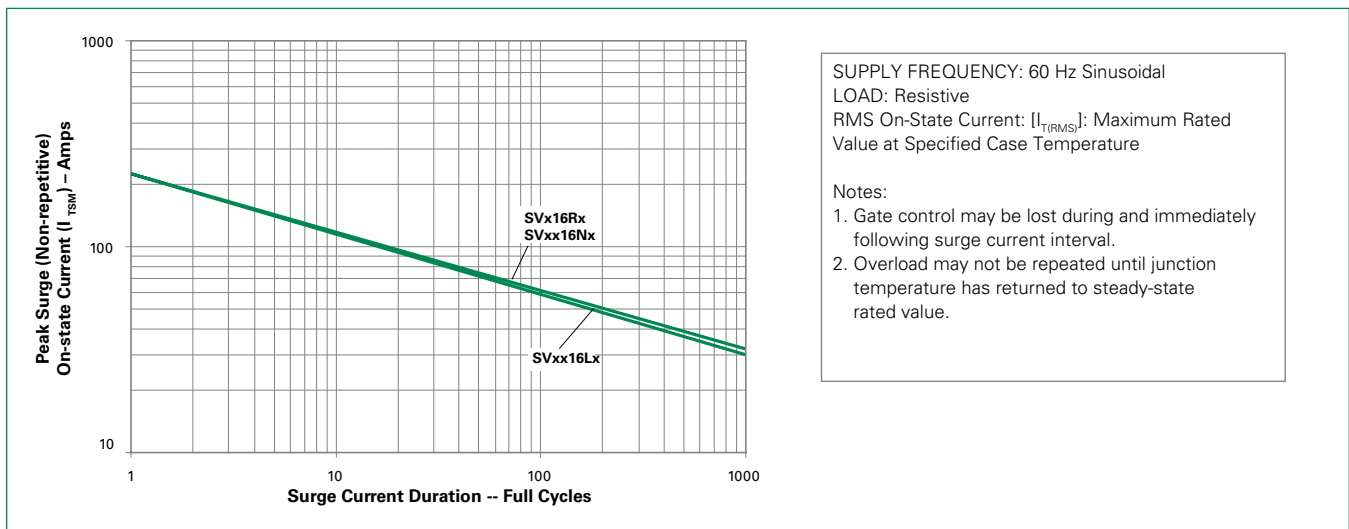
**Figure 8:**  
Peak Capacitor Discharge Current



**Figure 9:**  
Peak Capacitor Discharge Current Derating



**Figure 10:** Surge Peak On-State Current vs. Number of Cycles



# SVxx16xx series

## 16 Amp High Junction Temperature SCRs

### Soldering Parameters

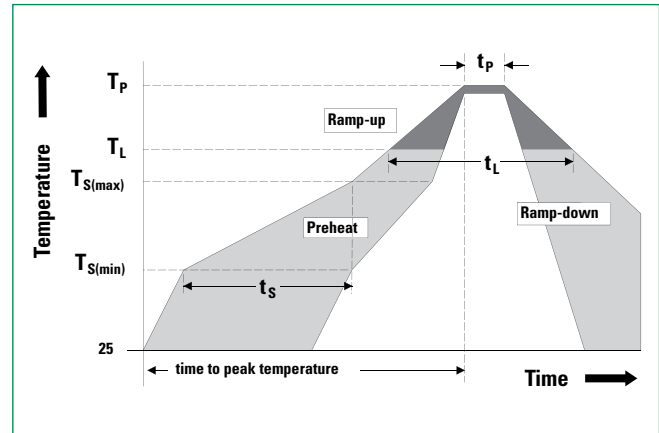
|                                                                        |                                    |                         |
|------------------------------------------------------------------------|------------------------------------|-------------------------|
| <b>Reflow Condition</b>                                                |                                    | Pb – Free assembly      |
| <b>Pre Heat</b>                                                        | - Temperature Min ( $T_{s(min)}$ ) | 150°C                   |
|                                                                        | - Temperature Max ( $T_{s(max)}$ ) | 200°C                   |
|                                                                        | - Time (min to max) ( $t_s$ )      | 60 – 180 secs           |
| <b>Average ramp up rate (Liquidus Temp) (<math>T_L</math>) to peak</b> |                                    | 5°C/second max          |
| <b><math>T_{s(max)}</math> to <math>T_L</math> - Ramp-up Rate</b>      |                                    | 5°C/second max          |
| <b>Reflow</b>                                                          | - Temperature ( $T_L$ ) (Liquidus) | 217°C                   |
|                                                                        | - Time ( $t_L$ )                   | 60 – 150 seconds        |
| <b>Peak Temperature (<math>T_p</math>)</b>                             |                                    | 260 <sup>+0/-5</sup> °C |
| <b>Time within 5°C of actual peak Temperature (<math>t_p</math>)</b>   |                                    | 20 – 40 seconds         |
| <b>Ramp-down Rate</b>                                                  |                                    | 5°C/second max          |
| <b>Time 25°C to peak Temperature (<math>T_p</math>)</b>                |                                    | 8 minutes Max.          |
| <b>Do not exceed</b>                                                   |                                    | 280°C                   |

### Physical Specifications

|                        |                                                        |
|------------------------|--------------------------------------------------------|
| <b>Terminal Finish</b> | 100% Matte Tin-plated                                  |
| <b>Body Material</b>   | UL Recognized compound meeting flammability rating V-0 |
| <b>Lead Material</b>   | Copper Alloy                                           |

### Design Considerations

Careful selection of the correct component for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the component rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including  $dv/dt$ ), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.



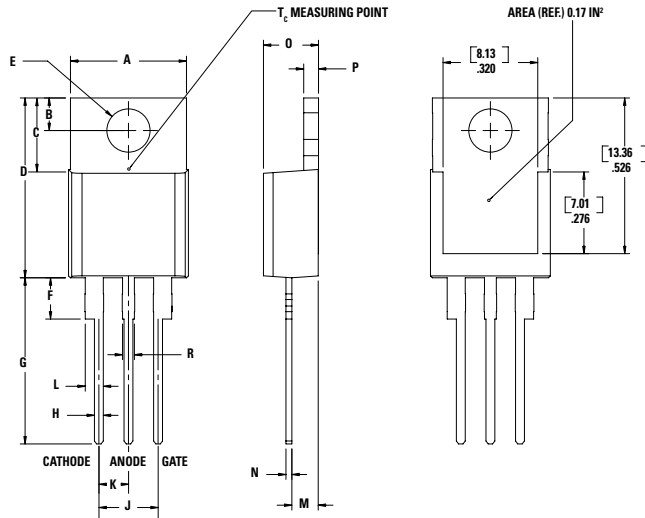
### Environmental Specifications

| Test                              | Specifications and Conditions                                                 |
|-----------------------------------|-------------------------------------------------------------------------------|
| <b>AC Blocking</b>                | MIL-STD-750, M-1040, Cond A<br>Applied Peak AC voltage @ 150°C for 1008 hours |
| <b>Temperature Cycling</b>        | MIL-STD-750, M-1051,<br>1000 cycles; -55°C to +150°C;<br>15-min dwell-time    |
| <b>Temperature/Humidity</b>       | EIA / JEDEC, JESD22-A101<br>1008 hours; 160V - DC: 85°C;<br>85% rel humidity  |
| <b>Resistance to Solder Heat</b>  | MIL-STD-750 Method 2031                                                       |
| <b>Solderability</b>              | ANSI/J-STD-002, category 3, Test A                                            |
| <b>Lead Bend</b>                  | MIL-STD-750, M-2036 Cond E                                                    |
| <b>Moisture Sensitivity Level</b> | Level 1, JEDEC-J-STD-020D                                                     |

# SVxx16xx series

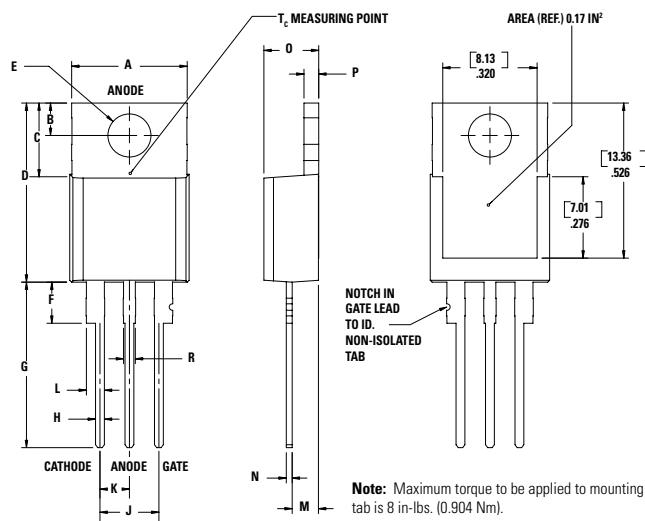
## 16 Amp High Junction Temperature SCRs

### Dimensions — TO-220AB (L-Package) — Isolated Mounting Tab



| Dimension | Inches |       | Millimeters |       |
|-----------|--------|-------|-------------|-------|
|           | Min    | Max   | Min         | Max   |
| A         | 0.380  | 0.420 | 9.65        | 10.67 |
| B         | 0.105  | 0.115 | 2.67        | 2.92  |
| C         | 0.230  | 0.250 | 5.84        | 6.35  |
| D         | 0.590  | 0.620 | 14.99       | 15.75 |
| E         | 0.142  | 0.147 | 3.61        | 3.73  |
| F         | 0.110  | 0.130 | 2.79        | 3.30  |
| G         | 0.540  | 0.575 | 13.72       | 14.61 |
| H         | 0.025  | 0.035 | 0.64        | 0.89  |
| J         | 0.195  | 0.205 | 4.95        | 5.21  |
| K         | 0.095  | 0.105 | 2.41        | 2.67  |
| L         | 0.060  | 0.075 | 1.52        | 1.91  |
| M         | 0.085  | 0.095 | 2.16        | 2.41  |
| N         | 0.018  | 0.024 | 0.46        | 0.61  |
| O         | 0.178  | 0.188 | 4.52        | 4.78  |
| P         | 0.045  | 0.060 | 1.14        | 1.52  |
| R         | 0.038  | 0.048 | 0.97        | 1.22  |

### Dimensions — TO-220AB (R-Package) — Non-Isolated Mounting Tab Common with Center Lead

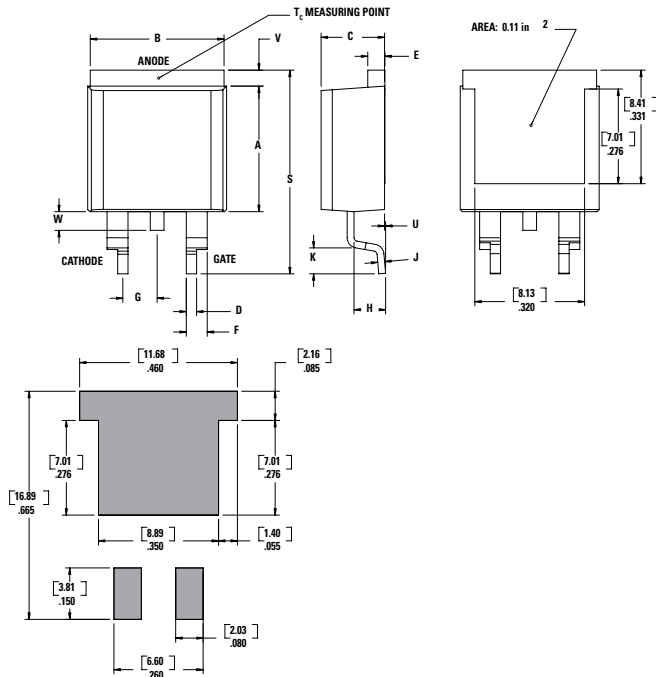


| Dimension | Inches |       | Millimeters |       |
|-----------|--------|-------|-------------|-------|
|           | Min    | Max   | Min         | Max   |
| A         | 0.380  | 0.420 | 9.65        | 10.67 |
| B         | 0.105  | 0.115 | 2.67        | 2.92  |
| C         | 0.230  | 0.250 | 5.84        | 6.35  |
| D         | 0.590  | 0.620 | 14.99       | 15.75 |
| E         | 0.142  | 0.147 | 3.61        | 3.73  |
| F         | 0.110  | 0.130 | 2.79        | 3.30  |
| G         | 0.540  | 0.575 | 13.72       | 14.61 |
| H         | 0.025  | 0.035 | 0.64        | 0.89  |
| J         | 0.195  | 0.205 | 4.95        | 5.21  |
| K         | 0.095  | 0.105 | 2.41        | 2.67  |
| L         | 0.060  | 0.075 | 1.52        | 1.91  |
| M         | 0.085  | 0.095 | 2.16        | 2.41  |
| N         | 0.018  | 0.024 | 0.46        | 0.61  |
| O         | 0.178  | 0.188 | 4.52        | 4.78  |
| P         | 0.045  | 0.060 | 1.14        | 1.52  |
| R         | 0.038  | 0.048 | 0.97        | 1.22  |

# SVxx16xx series

## 16 Amp High Junction Temperature SCRs

### Dimensions — TO- 263AB (N-package) — D2-Pak Surface Mount



| Dimension | Inches |       | Millimeters |       |
|-----------|--------|-------|-------------|-------|
|           | Min    | Max   | Min         | Max   |
| <b>A</b>  | 0.360  | 0.370 | 9.14        | 9.40  |
| <b>B</b>  | 0.380  | 0.420 | 9.65        | 10.67 |
| <b>C</b>  | 0.178  | 0.188 | 4.52        | 4.78  |
| <b>D</b>  | 0.025  | 0.035 | 0.64        | 0.89  |
| <b>E</b>  | 0.045  | 0.060 | 1.14        | 1.52  |
| <b>F</b>  | 0.060  | 0.075 | 1.52        | 1.91  |
| <b>G</b>  | 0.095  | 0.105 | 2.41        | 2.67  |
| <b>H</b>  | 0.092  | 0.102 | 2.34        | 2.59  |
| <b>J</b>  | 0.018  | 0.024 | 0.46        | 0.61  |
| <b>K</b>  | 0.090  | 0.110 | 2.29        | 2.79  |
| <b>S</b>  | 0.590  | 0.625 | 14.99       | 15.88 |
| <b>V</b>  | 0.035  | 0.045 | 0.89        | 1.14  |
| <b>U</b>  | 0.002  | 0.010 | 0.05        | 0.25  |
| <b>W</b>  | 0.040  | 0.070 | 1.02        | 1.78  |

### Product Selector

| Part Number | Voltage | Gate Sensitivity | Type         | Package |
|-------------|---------|------------------|--------------|---------|
|             | 600V    |                  |              |         |
| SVxx16L1    | X       | 6mA              | Standard SCR | TO-220L |
| SVxx16R1    | X       | 6mA              | Standard SCR | TO-220R |
| SVxx16N1    | X       | 6mA              | Standard SCR | TO-263  |
| SVxx16L2    | X       | 10mA             | Standard SCR | TO-220L |
| SVxx16R2    | X       | 10mA             | Standard SCR | TO-220R |
| SVxx16N2    | X       | 10mA             | Standard SCR | TO-263  |

Note: xx = Voltage/10

### Packing Options

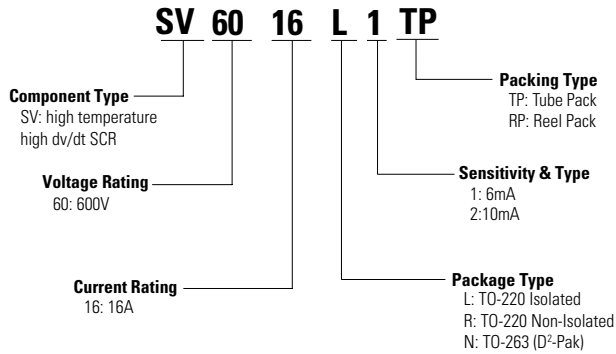
| Part Number | Marking  | Weight | Packing Mode     | Base Quantity      |
|-------------|----------|--------|------------------|--------------------|
| SVxx16LxTP  | SVxx16Ly | 2.2g   | Tube             | 1000 (50 per tube) |
| SVxx16RxTP  | SVxx16Ry | 2.2g   | Tube             | 1000 (50 per tube) |
| SVxx16NxTP  | SVxx16Ny | 1.6g   | Tube             | 1000 (50 per tube) |
| SVxx16NxRP  | SVxx16Ny | 1.6g   | Embossed Carrier | 500                |

Note: xx=voltage/10, x=sensitivity

# SVxx16xx series

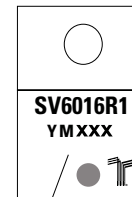
## 16 Amp High Junction Temperature SCRs

### Part Numbering System



### Part Marking System

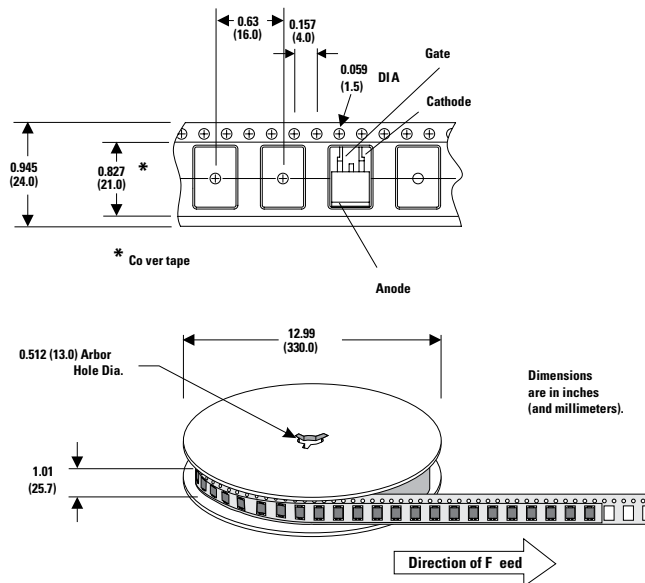
T0-220 AB - (L and R Package)  
T0-263 AB - (N Package)



**Date Code Marking**  
Y: Year Code  
M: Month Code  
XXX: Lot Trace Code

### TO-263 Embossed Carrier Reel Pack (RP) Specifications

Meets all EIA-481-2 Standards



**Disclaimer Notice** - Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at <http://www.littelfuse.com/disclaimer-electronics>.